

Ph. 480-503-4295 | NOPP@FocusLCD.com

TFT | CHARACTER | UWVD | FSC | SEGMENT | CUSTOM | REPLACEMENT

TFT Display Module

Part Number E35RC-B-MW420-N

Overview:

- 3.5-inch TFT (64x85)
- 480 640
- 2-lane MIPI DSI Interface
- ‡ 'u erature
- All View, VA

- Blanview
- No Touch Panel
- 420 NITS
- TFT IC: ILI9806E
- RoHS Compliant



Description

This is a color active matrix TFT (Thin Film Transistor) LCD (Liquid Crystal Display) that uses amorphous silicon TFT as a switching device. This model is composed of a blanview type TFT LCD Panel, driver circuit and a backlight unit. The resolution of the 3.5" TFT LCD contains 480(RGB)x640 pixels and can display up to 16.7M colors.

TFT Features

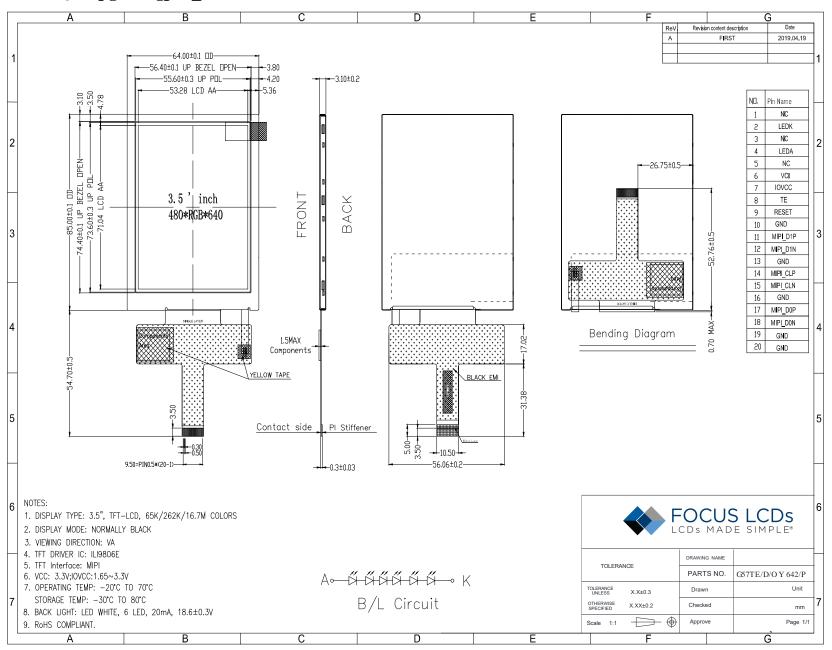
Low Input Voltage: 3.3V Display Colors: 16.7M Interface: 2-lane MIPI DSI

Complete Com	Specification	Unit	Note
General Information Items	Main Panel	Ont	Note
TFT Display area (AA)	53.28(H) x 71.04 (3.5 inch)	mm	-
Driver Element	TFT active matrix	-	-
Display Colors	16.7M	colors	-
Number of pixels	480(RGB)x640	pixels	-
TFT Pixel arrangement	RGB vertical stripe	-	-
Pixel Pitch	0.111 (H)x0.111 (V)	mm	-
Viewing angle	VA, All View	o'clock	-
TFT Controller IC	ILI9806E	-	-
TFT Interface	2-lane MIPI	-	_
Display mode	Blanview/ Normally Black	-	-
Operating temperature	-20-+70	°C	-
Storage temperature	-30-+80	°C	-

Mechanical Information

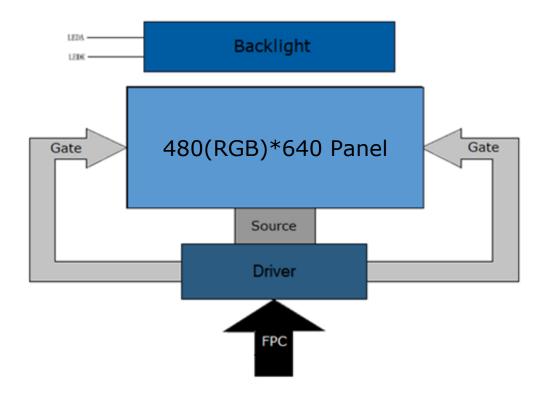
	Item	Min	Typ.	Max	Unit	Note
	Horizontal (H)		64		mm	-
Module	Vertical (V)		85		mm	-
Size	Depth (D)		3.1		mm	-
	Weight		35		g	

30" Qwwlpg'F lo gpulqpu





2. Block Diagram





Input Terminal Pin Assignment Recommended Connector: FH19C-20S-0.5SH(10) 3.

NO.	Symbol	Description	I/O
1	NC	Not connected	
2	LEDK	Cathode pin of the backlight	P
3	NC	Not connected	
4	LEDA	Anode pin of the backlight	P
5	NC	Not connected	
6	VCI	Supply voltage (3.3V)	P
7	IOVCC	I/O power supply voltage (1.65-3.3V)	P
8	TE	Tearing effect output	I
9	RESET	External reset signal. Initializes the chip at active low.	I
10	GND	Ground	P
11	D1P	MIPI DSI differential data pair lane 1	I/O
12	D1N	Will I DSI differential data pair faile I	1/0
13	GND	Ground	P
14	CLKP	MIDI DCI differential algebra main	I/O
15	CLKN	MIPI DSI differential clocking pair	1/0
16	GND	Ground	P
17	D0P	MIDI DCI 4:654:-1 4-4	I/O
18	D0N	MIPI DSI differential data pair lane 0	I/O
19	GND	Ground	P
20	GND	Ground	P

I: Input, O: Output, P: Power



4. LCD Optical Characteristics

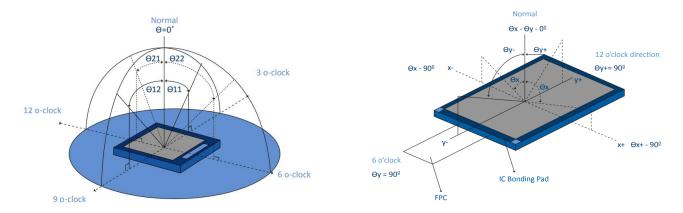
4.1 Optical Specifications

4.1 Optical S	pecification							
Item		Symbol	Condition	Min	Тур.	Max	Unit	Note
Color Gar	nut	S%			51.7		%	(3)
Contrast R	atio	CR		500	700		%	(2)
D Tr'	Rising				25			(4)
Response Time	Falling	TR+TF			25		ms	(4)
	3371 1	W_X	$\theta = 0$	0.2594	0.2994	0.3394		
	White	W _Y	Normal viewing angle	0.2899	0.3299	0.3699	- -	(5)(6)
	D 1	R_X		0.4975	0.5375	0.5775		
Color Filter	Red	R_{Y}		0.2928	0.3328	0.3728		
Chromaticity	C	G_X		0.2970	0.3370	0.3770		
	Green	G_{Y}		0.5346	0.5746	0.6146		
	Dl	B_X		0.1139	0.1539	0.1939		
	Blue	B_{Y}		0.0746	0.1146	0.1546		
		ΘL			80			
17:: A1-	Hor.	ΘR	CR≥10		80			(1)(6)
Viewing Angle		ΘΤ			80		degrees	(1)(6)
	Ver.	ΘΒ			80			
Option View D	irection			VA				(1)



Optical Specification Reference Notes:

(1) Definition of Viewing Angle: The viewing angle is the angle at which the contrast ratio is greater than 10. The viewing angles are determined for the horizontal or 3,9 o'clock direction and the vertical or 6,12 o'clock direction with respect to the optical axis which is normal to the LCD surface.

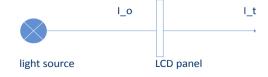


(2) Definition of Contrast Ratio (Cr): measured at the center point of panel. The contrast ratio (Cr) measured on a module, is the ratio between the luminance (Lw) in a full white area (R=G=B=1) and the luminance (Ld) in a dark area (R=G=B=0).

$$Cr = \frac{Lw}{Ld}$$

(3) Definition of transmittance (T%): The transmittance of the panel including the polarizers is measured with electrical driving. The equation for transmittance Tr is:

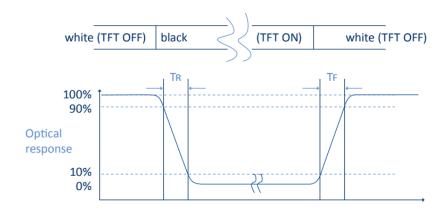
$$Tr = \frac{It}{Io} x 100\%$$



Io = the brightness of the light source.

It = the brightness after panel transmission

(4) Definition of Response Time (Tr, Tf): The rise time 'Tr' is defined as the time for luminance to change from 90% to 10% as a result of a change of the electrical condition. The fall time 'Tf' is defined as the time for luminance to change from 10% to 90% as a result of a change of the electrical condition.





(5) Definition of Color Gamut:

Measuring machine CFT-01. NTSC's Primaries: R(x,y,Y),G(x,y,Y), B(x,y,Y). FPM520 of Westar Display Technologies, INC., which utilized SR-3 for Chromaticity and BM-5A for other optical characteristics. The color chromaticity shall be calculated from the spectral data measured with all pixels first in red, green, blue and white. Measurements shall be made at the center of the panel.

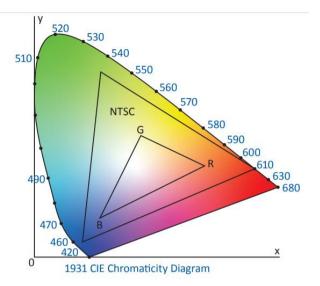
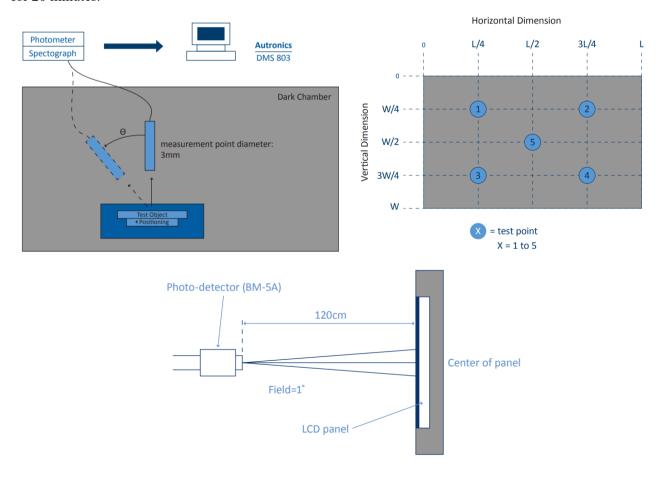


Fig. 1931 CIE chromacity diagram

Color gamut: $S = \frac{\text{Area of RGB triangle}}{\text{Area of NTSC triangle}} \times 100\%$

(6) Definition of Optical Measurement Setup:

The LCD module should be stabilized at a given temperature for 20 minutes to avoid abrupt temperature change during measuring. In order to stabilize the luminance, the measurement should be executed after lighting backlight for 20 minutes.





5. TFT Electrical Characteristics

5.1 Absolute Maximum Rating (Ta=25 °C, VSS=0V)

Characteristics	Symbol	Min	Max	Unit
Digital Supply Voltage	VCI	-0.3	4.6	V
DC/DC Supply Voltage	IOVCC	-0.3	4.6	
Operating Temperature	TOP	-20	+70	°C
Storage Temperature	TST	-30	+80	°C

NOTE: If the absolute maximum rating of the above parameters is exceeded, even momentarily, the quality of the product may be degraded. Absolute maximum ratings specify the values which the product may be physically damaged if exceeded. Be sure to use the product within the range of the absolute maximum ratings.

5.2 DC Electrical Characteristics

Characteristics	Symbol	Min	Тур.	Max	Unit	Note
Power Supply Voltage	VCI	2.5	3.3	3.6	V	
Digital Supply Voltage	IOVCC	1.65	1.8	3.6	V	
Normal Mode Current	IDD		38		mA	
Differential Input High Threshold Voltage	VIT+		0	50	mV	
Differential Inpu tLow Threshold Voltage	VIT-	-50	0		mV	
Single ended receiver input operation voltage	VIR	0.5		1.2	V	

5.3 MIPI DC Electrical Characteristics

Characteristics	Symbol	Min	Тур.	Max	Unit
Low power mode operating voltage	VLPH	1.1	1.2	1.3	V
Single ended input low voltage	VILHS	-40			mV
Single ended input high voltage	VIHHS			460	mV
Common mode voltage	VCMRXDC	70		330	mV
Differential input impedance	ZID	80	100	125	ohm
Pad signal voltage	VI	-50		1350	mV
Logic 0 input threshold	VIL	0		550	mV
Logic 1 input threshold	VIH	880		1350	mV
Output low level	VOL	-50		50	mV
Output high level	VOH	1.1	1.2	1.3	V



5.4 LED Backlight Characteristics

Item	Symbol	Min	Тур.	Max	Unit	Note
Forward Current	IF	15	20		mA	
Forward Voltage	VF		18.6		V	
LCM Luminance	LV	320	420		cd/m2	Note 3
LED lifetime	Hr		50000		hour	Note1 & 2
Uniformity	AVg	80			%	Note 3

The back-light system is edge-lighting type with 6 white LEDs.

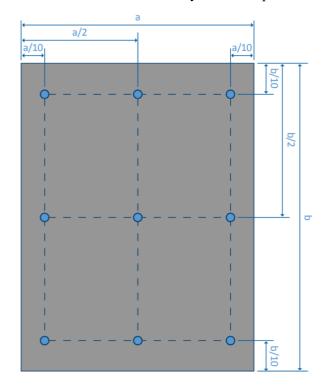
Note 1: LED lifetime (Hr) can be defined as the time in which it continues to operate under the condition: $Ta=25\pm3$ °C, typical IL value indicated in the above table until the brightness becomes less than 50%.

Note 2: The "LED lifetime" is defined as the module brightness decrease to 50% original brightness at Ta=25°C and IL=20mA. The LED lifetime could be decreased if operating IL is larger than 20mA. The constant current driving method is suggested.



Backlight LED Circuit

Note 3: Luminance Uniformity of these 9 points is defined as below:



$$Luminance = (\underbrace{Total\ Luminance\ of\ 9\ points}_{Q})$$

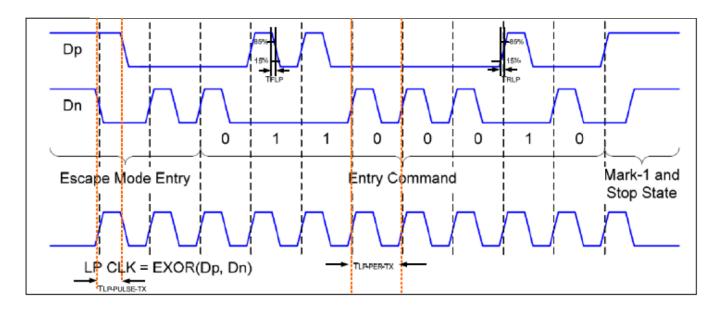
Uniformity = minimum luminance in 9 points(1-9) maximum luminance in 9 points(1-9)



6. MIPI AC Characteristics

6.1 LP Transmitter AC Specification

Pai	rameter	Symbol	Min	Тур.	Max	Unit	Note
15%-85% risi	ng and falling time	TRLP/TFLP			25	ns	
30%-85% risi	ng and falling time	Treot			35	ns	
Pulse width of LP	First LP XOR clock pulse after stop state or last pulse before stop state		40		1	ns	
exclusive OR clock	All other pulses	Tlp-pulse-tx	20			ns	
Period of	the LP XOR clock	Tlp-per-tx	90			mV/ns	
Slew rate	e @CLOAD=0pF		30		500	mV/ns	
Slew rate	e @CLOAD=5pF		30		200	mV/ns	
Slew rate	@CLOAD=20pF	dV/dtSR	30		150	mV/ns	
Slew rate	@CLOAD=70pF		30		100	mV/ns	
Load	capacitance	Trlp			70	pF	

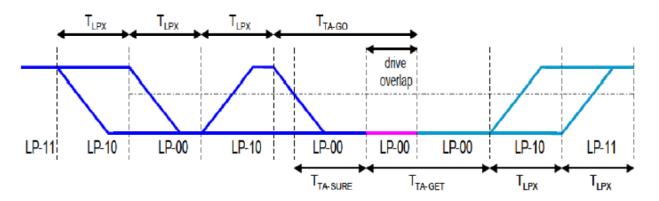


6.2 Turnaround Procedure

Parameter	Symbol	Min	Тур.	Max	Unit	Note
Length of any low power state period: master side	TLPX	50	-	75	ns	
Length of any low power state period: slave side	TLPX	50	55.56	58.34	ns	
Ratio of TLPX(Master)/TLPX(Slave) between master and slave side	RatioTLPX	2/3	-1	3/2	ns	
Time-out before new TX side start driving	TTA-Sure	TLPX		2 TLPX	ns	
Time to drive LP-00 by new TX	Tta-get		5 TLPX		ns	
Time to drive LP-00 after turnaround request	TTA-GO		4 TLPX		ns	

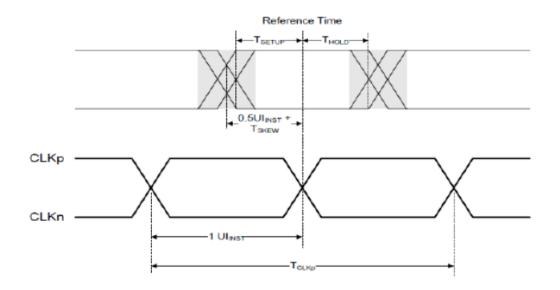
11





6.3 High Speed Transmission

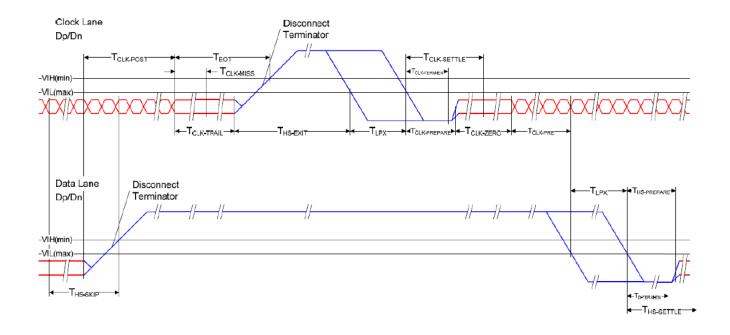
Parameter	Symbol	Min	Тур.	Max	Unit	Note
UI Instantaneous	Ulinst	2		12.5	ns	
Data to clock skew (measured at transmitter)	TSKEW(TX)	-0.15		0.15	Ulinst	
Data to clock setup time (measured at receiver)	TSETUP(RX)	0.15			Ulinst	
Data to clock hold time (measured at receiver)	THOLD(RX)	0.15			Ulinst	
200/ 000/ vice and fall hims		150			ps	
20%-80% rise and fall time	TR, TF				Ulinst	





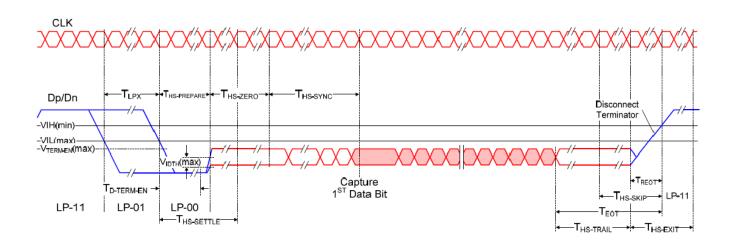
6.4 High Speed Clock Transmission

Parameter	Symbol	Min	Тур.	Max	Unit
Time that the transmitter shall continue sending HS clock after the last associated data lane has transitioned to LP mode	Tclk-post	60+52UI	I	1	ns
Detection time that the clock has stopped toggling	Tclk-miss			60	ns
Time to drive LP-00 to prepare for HS clock transmission	Tclk-prepare	38	-	95	ns
Minimum lead HS-0 drive period before starting clock	TCLK-PREPARE+TCLK-	300			ns
Time to enable clock lane receiver line termination measured from when Dn crosses VILMAX	Ths-term-en			38	ns
Minimum time that the HS clock must be prior to any associated data lane beginning the transmission from LP to HS mode	TCLK-PRE	8			UI
Time to drive HS differential state after last payload clock bit of a HS transmission burst	Tclk-trail	60			ns





6.5 High Speed Data Transmission in Bursts





7. Cautions and Handling Precautions

7.1 Handling and Operating the Module

- 1. When the module is assembled, it should be attached to the system firmly. Do not warp or twist the module during assembly work.
- 2. Protect the module from physical shock or any force. In addition to damage, this may cause improper operation or damage to the module and back-light unit.
- 3. Note that polarizer is very fragile and could be easily damaged. Do not press or scratch the surface.
- 4. Do not allow drops of water or chemicals to remain on the display surface. If you have the droplets for a long time, staining and discoloration may occur.
- 5. If the surface of the polarizer is dirty, clean it using some absorbent cotton or soft cloth.
- 6. The desirable cleaners are water, IPA (Isopropyl Alcohol) or Hexane. Do not use ketene type materials (ex. Acetone), Ethyl alcohol, Toluene, Ethyl acid or Methyl chloride. It might permanent damage to the polarizer due to chemical reaction.
- 7. If the liquid crystal material leaks from the panel, it should be kept away from the eyes or mouth. In case of contact with hands, legs, or clothes, it must be washed away thoroughly with soap.
- 8. Protect the module from static; it may cause damage to the CMOS ICs.
- 9. Use fingerstalls with soft gloves in order to keep display clean during the incoming inspection and assembly process.
- 10. Do not disassemble the module.
- 11. Protection film for polarizer on the module shall be slowly peeled off just before use so that the electrostatic charge can be minimized.
- 12. Pins of I/F connector shall not be touched directly with bare hands.
- 13. Do not connect, disconnect the module in the "Power ON" condition.
- 14. Power supply should always be turned on/off by the item Power On Sequence & Power Off Sequence.

7.2 Storage and Transportation.

- 1. Do not leave the panel in high temperature, and high humidity for a long time. It is highly recommended to store the module with temperature from 0 to 35 °C and relative humidity of less than 70%
- 2. Do not store the TFT-LCD module in direct sunlight.
- 3. The module shall be stored in a dark place. When storing the modules for a long time, be sure to adopt effective measures for protecting the modules from strong ultraviolet radiation, sunlight, or fluorescent light.
- 4. It is recommended that the modules should be stored under a condition where no condensation is allowed. Formation of dewdrops may cause an abnormal operation or a failure of the module. In particular, the greatest possible care should be taken to prevent any module from being operated where condensation has occurred inside.
- 5. This panel has its circuitry FPC on the bottom side and should be handled carefully in order not to be stressed.